**10/5**82802 **AP3 Rec'd PCT/PTO** 14 JUN 2005 06/14/2006 Pocket, No.: SUG-192-PCT

S/N: TBA

### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Serial No.: TO BE ASSIGNED Confirmation No.: TO BE ASSIGNED

Applicant: Toru YAMADA, et al. Art Unit: TO BE ASSIGNED

Filed: June 14, 2006 Examiner: TO BE ASSIGNED

Docket No: SUG-192-PCT Customer No: 28892

For: Vapor Phase Growth Apparatus and Method of Fabricating

Epitaxial Wafer

# INFORMATION DISCLOSURE STATEMENT PURSUANT TO 37 C.F.R. §§ 1.56, 1.97, and 1.98

US Patent & Trademark Office Customer Service Window Randolph Building 401 Dulany Street Alexandria, VA 22314

Sir:

In compliance with the dictates of 37 C.F.R. §§ 1.56, 1.97, and 1.98, Applicant hereby submits an Information Disclosure Statement.

Three of the attached documents are mentioned in the present specification and a brief description of their relevance can be found therein.

Applicant hereby reports the issuance of a Search Report in the corresponding Japanese application. A copy of that Search Report and three of the references cited therein (listed on attached PTO Form 1449) is attached hereto.

S/N: TBA <u>INFORMATION DISCLOSURE STATEMENT TRANSMITTAL - PAGE 2 of 2</u>

In accordance with MPEP § 609 III A(2), copies of US patent documents are not attached for applications filed after June 30,

2003 (MPEP Rev. 2, May 2004, page 600-128).

It is respectfully requested that the Examiner consider each of these references and indicate such consideration by enclosing an appropriately initialled copy of the enclosed form PTO-1449 with the next communication from the Patent Office.

Respectfully submitted,

Req. No. 21,091

Signing for

Ronald R. Snider Attorney of Record Reg. No. 24,962

Date: June 14, 2006

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#### **INFORMATION DISCLOSURE STATEMENT - PTO FORM 1449**

U.S. PATENT DOCUMENTS					
Examiner Initials*	U.S. Patent Document Number	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY		
	6,153,260	Paul B. Comita et al.	11-28-2000		

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Foreign Patent Document Number	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	T**		
	JP 2002-231641 w/ English Abstract	Shinetsu Handotai KK Nagano Electronics Ind	08-16-2002			
	JP 2002-198316 w/ English Abstract	Shinetsu Handotai KK Nagano Electronics Ind	07-12-2002			
	JP 2001-44125 w/ English Abstract	Applied Materials Inc	02-16-2001			
	JP 2000-331939 w/ English Abstract	Applied Materials Inc	11-30-2000			
	JP 11-45861	Applied Materials Inc	02-16-1999	2		
	JP 7-193015	Applied Materials Inc	07-28-1995	Х		
	EP 0 637 058 A1	Applied Materials Inc	02-01-1995			
	EP 0 637 058 B1	Applied Materials Inc	02-01-1995			

S/N: TBA

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## INFORMATION DISCLOSURE STATEMENT - PTO FORM 1449 - Page 2 of 2

Examiner Signature	Date	
Signature	Considered	

<sup>\*</sup>Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>\*\*</sup>Applicant is to place a check mark here if English language translation is attached